# Switch Mode Power Rectifiers

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

#### Features

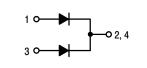
- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- These are Pb–Free Devices\*
- **Mechanical Characteristics:**
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

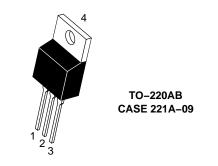


#### **ON Semiconductor®**

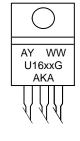
www.onsemi.com

### ULTRAFAST RECTIFIERS 16 AMPERES, 100–600 VOLTS





#### MARKING DIAGRAM



A = Assembly Location

- Y = Year WW = Work Week
- U16xx = Device Code
  - xx = 10, 15, 20, 40 or 60
- G = Pb-Free Package
- KA = Diode Polarity

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### MAXIMUM RATINGS

Rating		Symbol	10CT	15CT	20CT	40CT	60CT	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	150	200	400	600	V	
Average Rectified Forward Current Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C	Per Leg Total Device	I <sub>F(AV)</sub>	8.0 16			A			
Peak Rectified Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz), T <sub>C</sub> = 150°C	Per Diode Leg	I <sub>FM</sub>	16					A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	100					A	
Operating Junction Temperature and Storage Temperature		T <sub>J</sub> , T <sub>stg</sub>	-65 to +175					°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	Value	Unit	
Maximum Thermal Resistance, Junction-to-Case	$R_{\thetaJC}$	3.0	2.0	°C/W

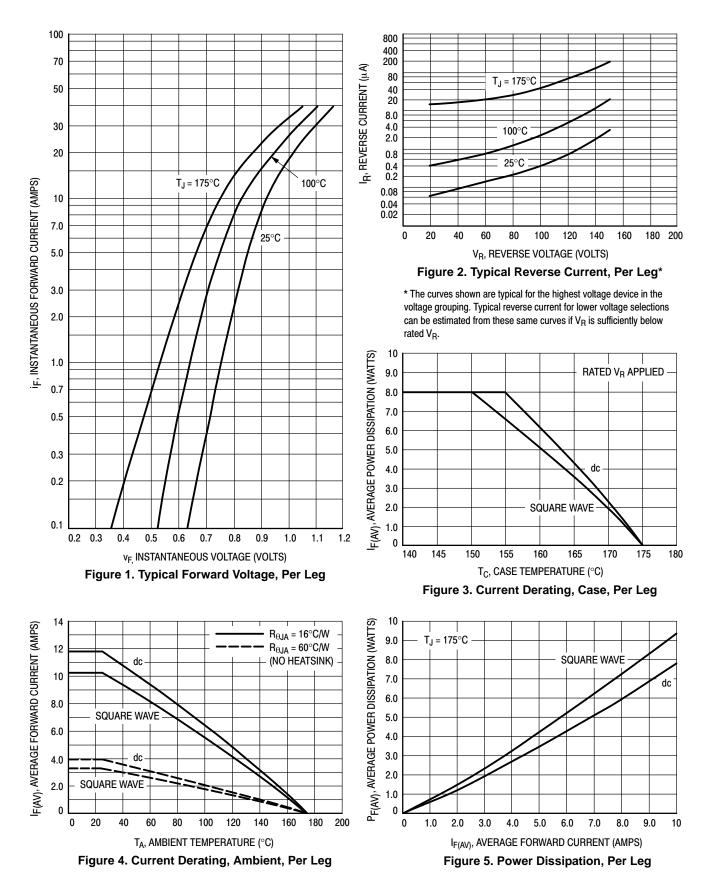
#### ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$ ) ( $i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$ )	VF	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 150^{\circ}C$ ) (Rated DC Voltage, $T_C = 25^{\circ}C$ )	i <sub>R</sub>	250 5.0	500 10		μΑ
Maximum Reverse Recovery Time $(I_F = 1.0 \text{ A}, \text{ di/dt} = 50 \text{ A/}\mu\text{s})$ $(I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{REC} = 0.25 \text{ A})$	t <sub>rr</sub>	35 25	60 50		ns

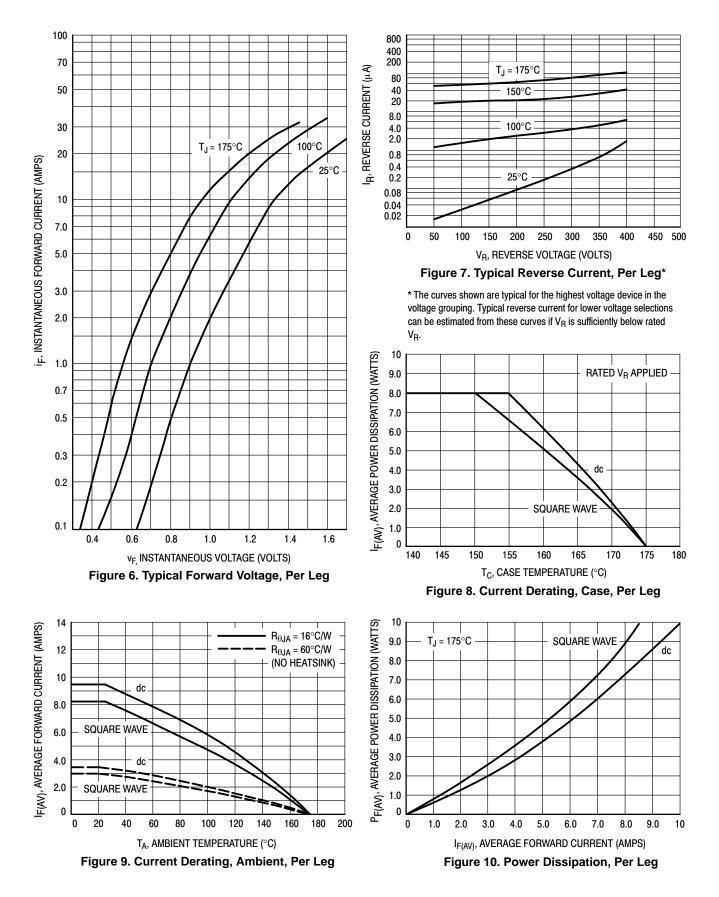
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width =  $300 \,\mu$ s, Duty Cycle  $\leq 2.0\%$ 

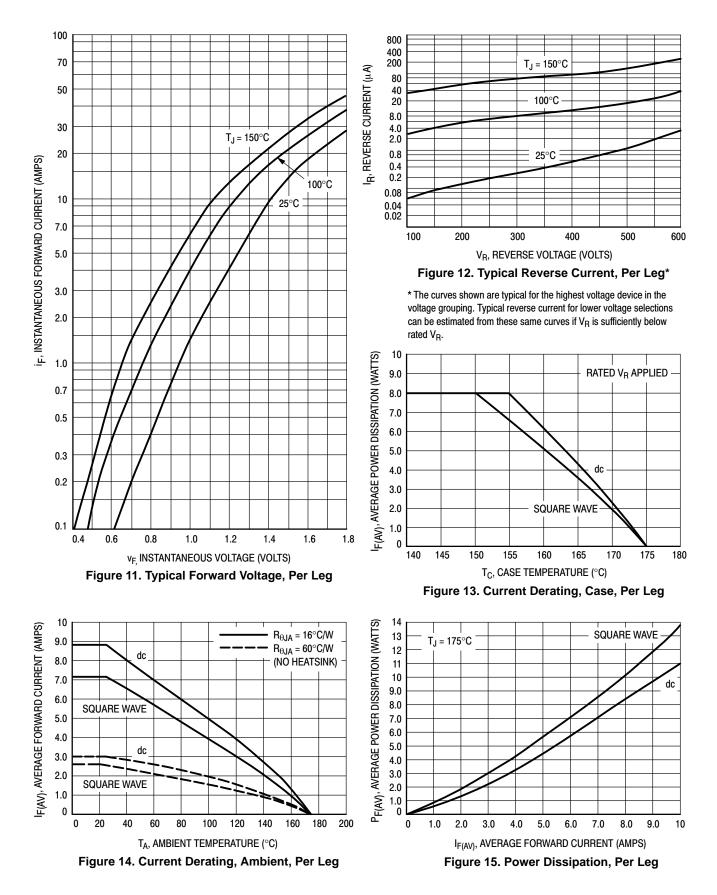
#### MUR1610CT, MUR1615CT, MUR1620CT

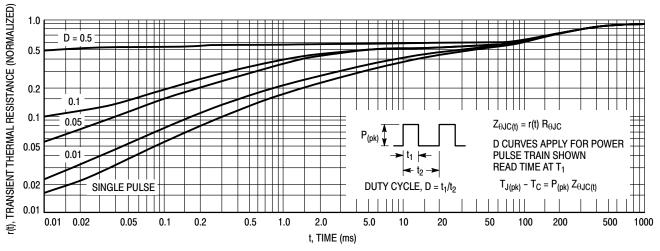


#### MUR1640CT



#### MUR1660CT







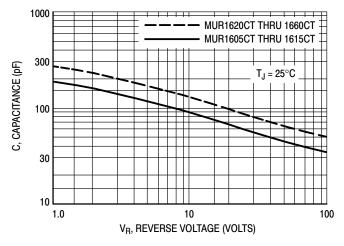


Figure 17. Typical Capacitance, Per Leg

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MUR1610CTG	TO-220 (Pb-Free)	
MUR1615CTG	TO-220 (Pb-Free)	
MUR1620CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1640CTG	TO-220 (Pb-Free)	
MUR1660CTG	TO-220 (Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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		TO-220 CASE 221A ISSUE AK						DATE	13 JAN 2022
SCALE 1:1			1. C 2. C 3. C	CONTR DIMEN LEAD	ROLLING DI ISION Z DEI D IRREGULA	MENSION FINES A ZO ARITIES AR	ONE WHERE AL E ALLOWED.		
			4. N	лах м	VIDTHFOR	F102 DEV	ICE = 1.35MM		
			Г		INC	HES	MILLIM	ETERS	
				ым 🛛	MIN.	MAX.	MIN.	MAX.	
	2 3			A	0.570	0.620	14.48	15.75	
				в	0.380	0.415	9.66	10.53	
н —	₩₩			с	0.160	0.190	4.07	4.83	
	7 \7	H I		D	0.025	0.038	0.64	0.96	
z_				F	0.142	0.161	3.60	4.09	
<u> </u>	I K			G	0.095	0.105	2.42	2.66	
				н	0.110	0.161	2.80	4.10	
	Щ Щ <u> </u>	Ü I		J	0.014	0.024	0.36	0.61	
	Г <mark>і</mark>			к	0.500	0.562	12.70	14.27	
V — + I I-	►- <b>  </b> ``.			L	0.045	0.060	1.15	1.52	
G <del></del>	.  <mark> </mark> <sup></sup> J <sup>−</sup>			N	0.190	0.210	4.83	5.33	
· · · ·	- <b>→  </b> D			Q	0.100	0.120	2.54	3.04	
	N 🖛			R	0.080	0.110	2.04	2.79	
				s	0.045	0.055	1.15	1.41	
				т	0.235	0.255	5.97	6.47	
				U	0.000	0.050	0.00	1.27	
				V	0.045		1.15		
				Z		0.080		2.04	
2. 3. 4. STYLE 5: PIN 1. 2.	BASE         PIN 1.           COLLECTOR         2.           EMITTER         3.           COLLECTOR         4.           STYLE 6:         GATE           DRAIN         2.	EMITTER COLLECTOR EMITTER ANODE CATHODE	IN 1. CAT 2. ANO 3. GAT 4. ANO LE 7: IN 1. CAT 2. ANO	ode Te ode Thode ode		2. 3. 4. STYLE 8: PIN 1. 2.	MAIN TERMINAL MAIN TERMINAL GATE MAIN TERMINAL CATHODE ANODE	2	
4. STYLE 9: PIN 1.	DRAIN 4. STYLE 10 GATE PIN 1.	ANODE CATHODE GATE P SOURCE	3. CAT 4. ANO LE 11: IN 1. DR/ 2. SOU	ode Ain		4. STYLE 12: PIN 1.	EXTERNAL TRIP ANODE MAIN TERMINAL MAIN TERMINAL	. 1	
3.	EMITTER 3.	DRAIN SOURCE	3. GAT 4. SOL	ΤE		3.	GATE NOT CONNECTI		

 
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